

# GP2S24J0000F Series

Detecting Distance : 0.7mm  
Phototransistor Output,  
Compact Reflective  
Photointerrupter



## ■ Description

GP2S24J0000F Series is a compact-package, photo-transistor output, reflective photointerrupter, with emitter and detector facing the same direction in a molding that provides non-contact sensing. The compact package series is a result of unique technology, combining transfer and injection molding, that also blocks visible light to minimize false detection.

## ■ Features

1. Reflective with Phototransistor Output
2. Highlights :
  - Compact Size
3. Key Parameters :
  - Optimal Sensing Distance : 0.7mm
  - Package : 4x3x1.7mm
  - Visible light cut resin package
4. Lead free and RoHS directive compliant

## ■ Agency approvals/Compliance

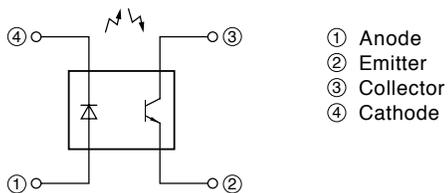
1. Compliant with RoHS directive

## ■ Applications

1. Detection of object presence or motion.
2. Example : printer, optical storage

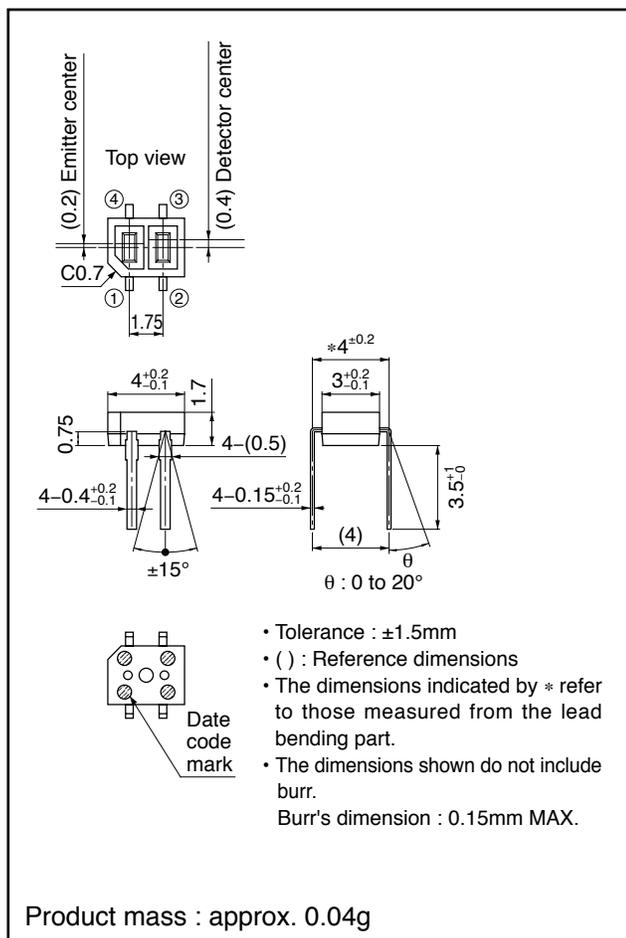


## Internal Connection Diagram



## Outline Dimensions

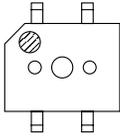
(Unit : mm)



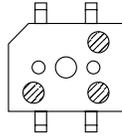
Plating material : SnCu (Cu : TYP. 2%)

## Date code (Symbol)

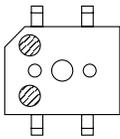
January



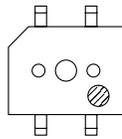
July



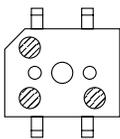
February



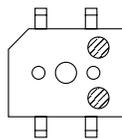
August



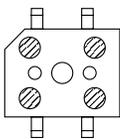
March



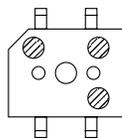
September



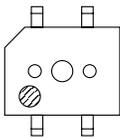
April



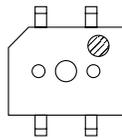
October



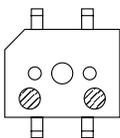
May



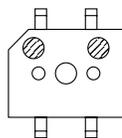
November



June



December



## Rank mark

There is no rank indicator.

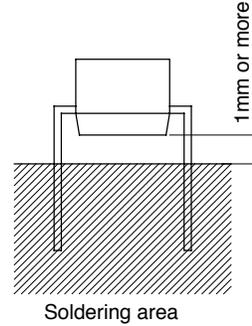
## Country of origin

Japan

### ■ Absolute Maximum Ratings (T<sub>a</sub>=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I <sub>F</sub>	50	mA
	Reverse voltage	V <sub>R</sub>	6	V
	Power dissipation	P	75	mW
Output	Collector-emitter voltage	V <sub>CEO</sub>	35	V
	Emitter-collector voltage	V <sub>ECO</sub>	6	V
	Collector current	I <sub>C</sub>	20	mA
	Collector power dissipation	P <sub>C</sub>	75	mW
Total power dissipation		P <sub>tot</sub>	100	mW
Operating temperature		T <sub>opr</sub>	-25 to +85	°C
Storage temperature		T <sub>stg</sub>	-40 to +100	°C
*1 Soldering temperature		T <sub>sol</sub>	260	°C

\*1 For 5s or less



### ■ Electro-optical Characteristics (T<sub>a</sub>=25°C)

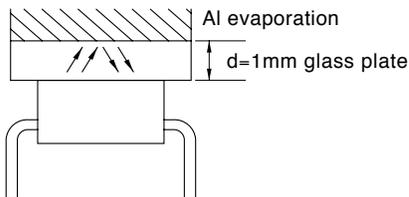
Parameter		Symbol	Condition	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> =20mA	-	1.2	1.4	V	
	Reverse current	I <sub>R</sub>	V <sub>R</sub> =6V	-	-	10	μA	
Output	Collector dark current	I <sub>CEO</sub>	V <sub>CE</sub> =20V	-	1	100	nA	
Transfer characteristics	*2 Collector Current		I <sub>C</sub>	I <sub>F</sub> =4mA, V <sub>CE</sub> =2V	20	45	120	μA
	Response time	Rise time	t <sub>r</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =100μA, R <sub>L</sub> =1kΩ, d=1mm	-	20	100	μs
		Fall time	t <sub>f</sub>		-	20	100	
	*3 Leak current		I <sub>LEAK</sub>	I <sub>F</sub> =4mA, V <sub>CE</sub> =2V	-	-	100	nA

\*2 The condition and arrangement of the reflective object are shown below.  
The rank splitting of collector current (I<sub>C</sub>) shall be executed according to the table below.

Rank	Collector current, I <sub>C</sub> [μA] (I <sub>F</sub> =4mA, V <sub>CE</sub> =2V)	Package sleeve color
A	20 to 42	Yellow
B	34 to 71	Transparent
C	58 to 120	Green

\*3 Without reflective object.

### ● Test Condition and Arrangement for Collector Current



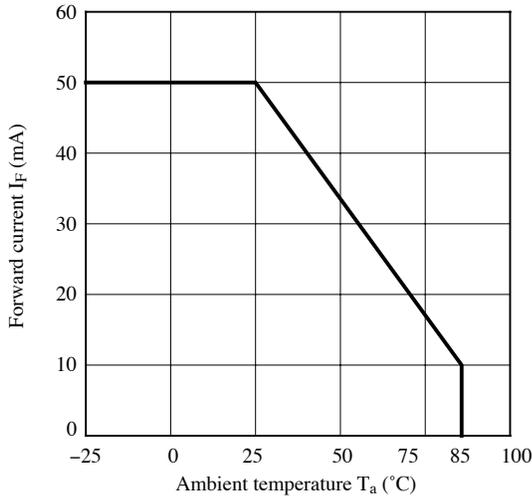
**■ Model Line-up**

Model No.	Rank	Collector current $I_C[\mu A]$ ( $I_F=4mA$ , $V_{CE}=2V$ , $T_a=25^\circ C$ )
<b>GP2S24J0000F</b>	A, B or C	20 to 120
<b>GP2S24BJ000F</b>	B	34 to 71
<b>GP2S24CJ000F</b>	C	58 to 120
<b>GP2S24ABJ00F</b>	A or B	20 to 71
<b>GP2S24BCJ00F</b>	B or C	34 to 120

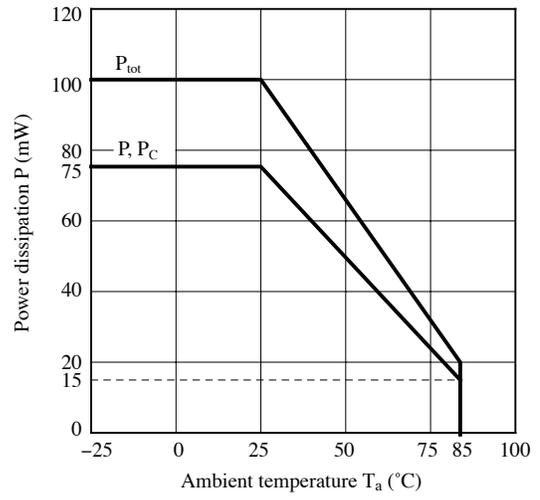
\* The ratio of each rank can not be guaranteed.

Please contact a local SHARP sales representative to inquire about production status.

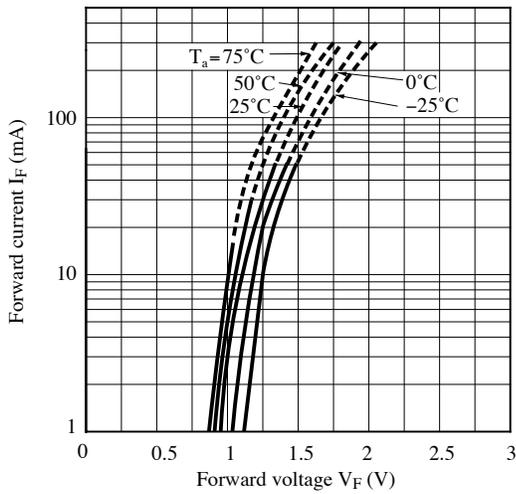
**Fig.1 Forward Current vs. Ambient Temperature**



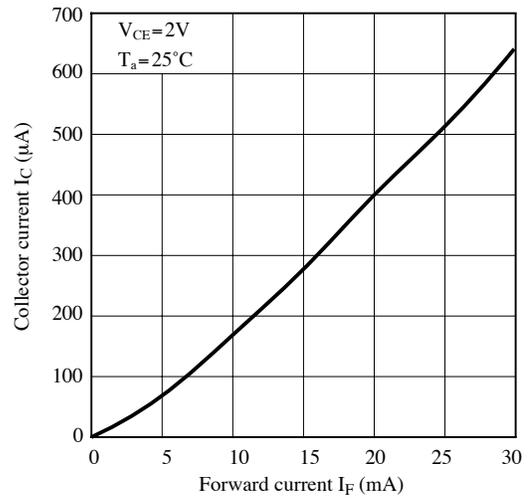
**Fig.2 Power Dissipation vs. Ambient Temperature**



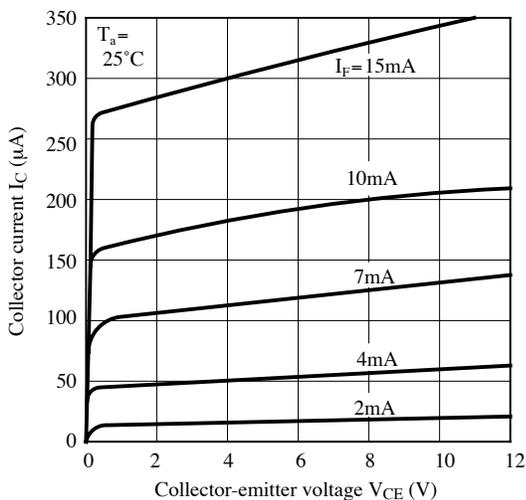
**Fig.3 Forward Current vs. Forward Voltage**



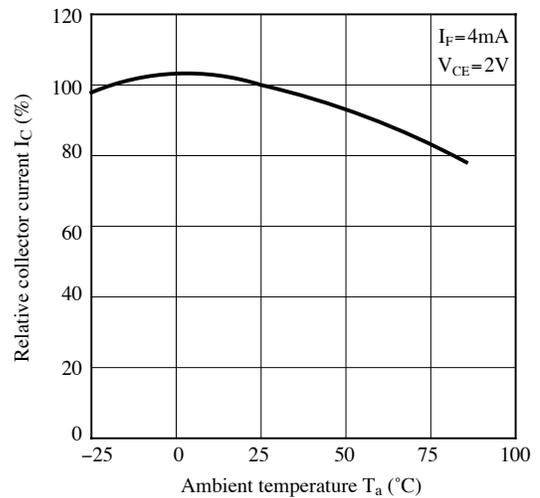
**Fig.4 Collector Current vs. Forward Current**



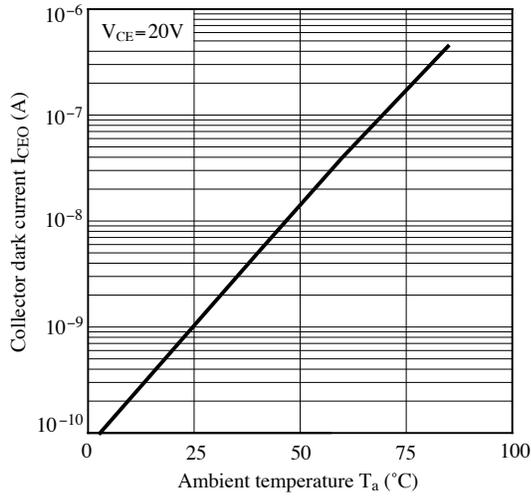
**Fig.5 Collector Current vs. Collector-Emitter Voltage**



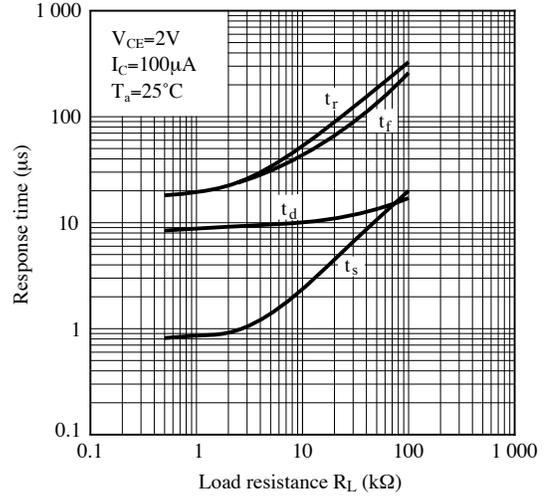
**Fig.6 Relative Collector Current vs. Ambient Temperature**



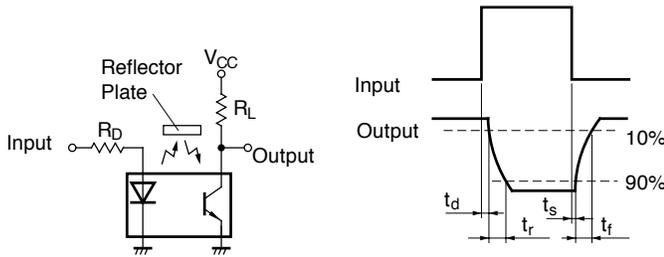
**Fig.7 Collector Dark Current vs. Ambient Temperature**



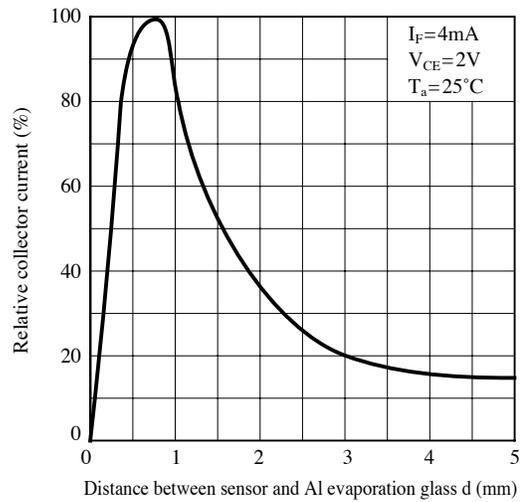
**Fig.8 Response Time vs. Load Resistance**



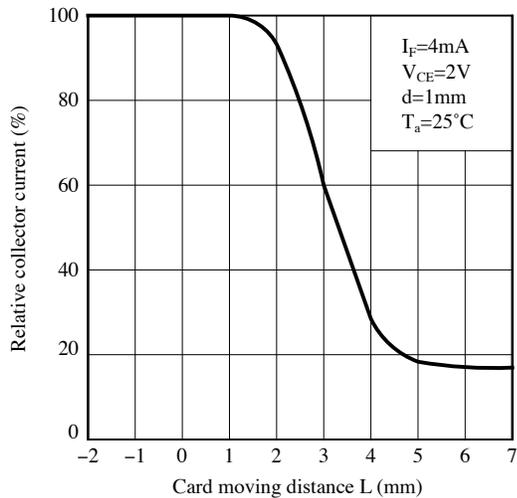
**Fig.9 Test Circuit for Response Time**



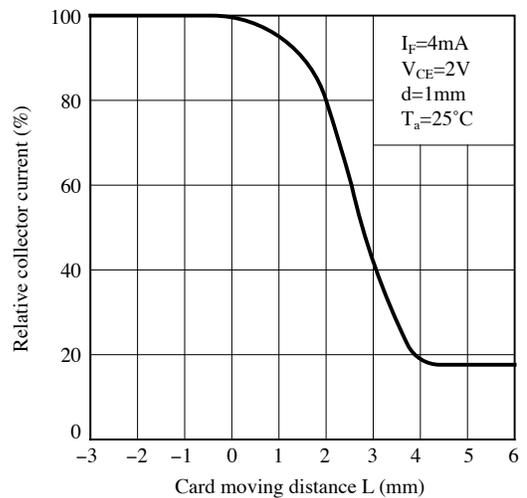
**Fig.10 Relative Collector Current vs. Distance (Reference value)**



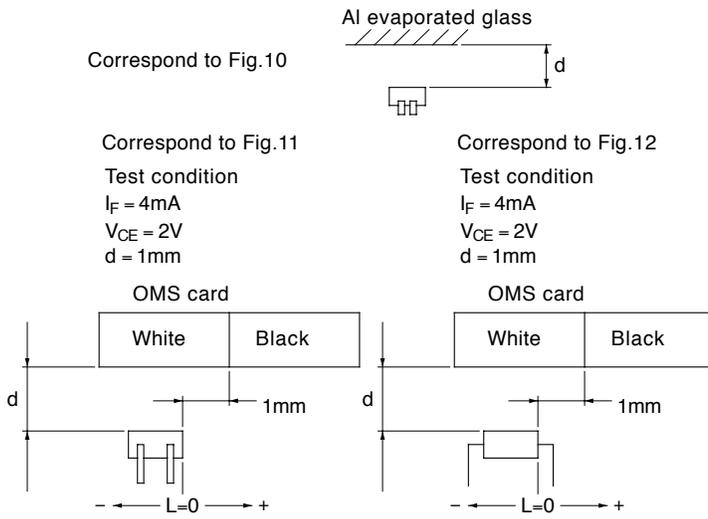
**Fig.11 Detecting Position Characteristics (1)**



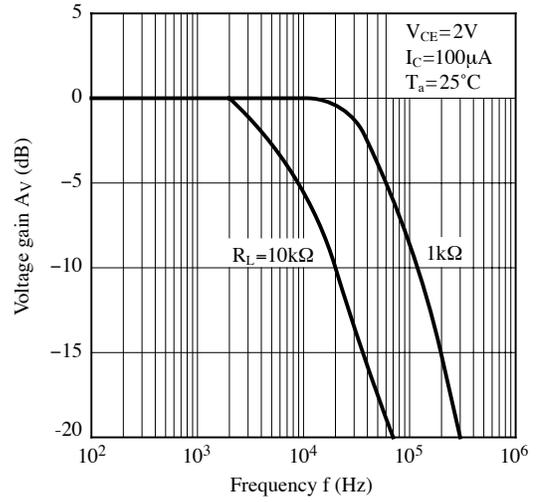
**Fig.12 Detecting Position Characteristics (2)**



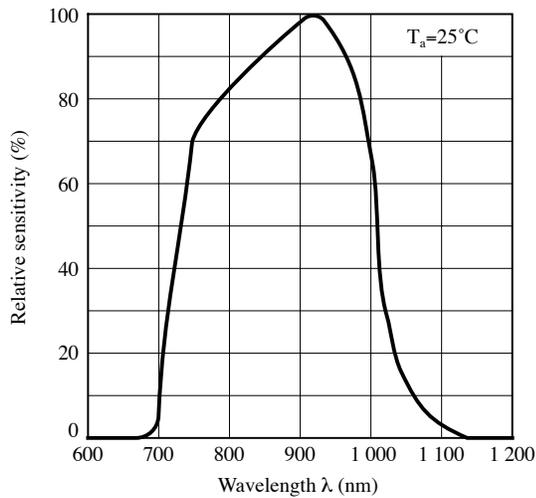
**Fig.13 Test Condition for Distance & Detecting Position Characteristics**



**Fig.14 Frequency Response**



**Fig.15 Spectral Sensitivity (Detecting Side)**



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.

## ■ Design Considerations

### ● Design guide

1) Prevention of detection error

To prevent photointerrupter from faulty operation caused by external light, do not set the detecting face to the external light.

2) Distance characteristic

Please refer to Fig.10 (Relative collector current vs. Distance) to set the distance of the photointerrupter and the object.

This product is not designed against irradiation and incorporates non-coherent IRED.

### ● Degradation

In general, the emission of the IRED used in photointerrupter will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

### ● Parts

This product is assembled using the below parts.

#### • Photodetector (qty. : 1)

Category	Material	Maximum Sensitivity wavelength (nm)	Sensitivity wavelength (nm)	Response time (μs)
Phototransister	Silicon (Si)	930	700 to 1 200	20

#### • Photo emitter (qty. : 1)

Category	Material	Maximum light emitting wavelength (nm)	I/O Frequency (MHz)
Infrared emitting diode (non-coherent)	Gallium arsenide (GaAs)	950	0.3

#### • Material

Case	Lead frame	Lead frame plating
Black polyphenylene	42Alloy	SnCu plating

**■ Manufacturing Guidelines****● Soldering Method**

## Flow Soldering:

Soldering should be completed below 260°C and within 5 s.

Soldering area is 1mm or more away from the bottom of housing.

Please take care not to let any external force exert on lead pins.

Please don't do soldering with preheating, and please don't do soldering by reflow.

## Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the cooling and soldering conditions.

**● Cleaning instructions**

## Solvent cleaning :

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

## Ultrasonic cleaning :

Do not execute ultrasonic cleaning.

## Recommended solvent materials :

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.

**● Presence of ODC**

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).

**■ Package specification****● Sleeve package**

## Package materials

Sleeve : Polystyrene

Stopper : Styrene-Butadiene

## Package method

MAX. 50 pcs. of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers.

MAX. 40 sleeves in one case.

## Color of sleeve

Rank classification is distinguished by the color of the sleeve as shown in the table below.

But the ratio of each rank can not be guaranteed.

Rank	Color of sleeve
A	Yellow
B	Transparent
C	Green

### ■ Important Notices

· The circuit application examples in this publication are provided to explain representative applications of SHARP devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes no responsibility for any problems related to any intellectual property right of a third party resulting from the use of SHARP's devices.

· Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARP reserves the right to make changes in the specifications, characteristics, data, materials, structure, and other contents described herein at any time without notice in order to improve design or reliability. Manufacturing locations are also subject to change without notice.

· Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet nor meet the following conditions:

(i) The devices in this publication are designed for use in general electronic equipment designs such as:

- Personal computers
- Office automation equipment
- Telecommunication equipment [terminal]
- Test and measurement equipment
- Industrial control
- Audio visual equipment
- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- Traffic signals
- Gas leakage sensor breakers
- Alarm equipment
- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- Space applications
- Telecommunication equipment [trunk lines]
- Nuclear power control equipment
- Medical and other life support equipment (e.g., scuba).

· If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Law of Japan, it is necessary to obtain approval to export such SHARP devices.

· This publication is the proprietary product of SHARP and is copyrighted, with all rights reserved. Under the copyright laws, no part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, for any purpose, in whole or in part, without the express written permission of SHARP. Express written permission is also required before any use of this publication may be made by a third party.

· Contact and consult with a SHARP representative if there are any questions about the contents of this publication.